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** CONTINUING DATA *****

NOTE *PR*

** FOREIGN APPLICATIONS *****

JAPAN 2002-336669 11/20/2002 *PR*

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
 ** 10/20/2003

Foreign Priority claimed 35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance	STATE OR COUNTRY JAPAN	SHEETS DRAWING 14	TOTAL CLAIMS 18	INDEPENDENT CLAIMS 2
Verified and Acknowledged	Examiner's Signature <i>[Signature]</i> Initials <i>[Initials]</i>				

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 22850
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TITLE
 Semiconductor device including gate electrode for applying tensile stress to silicon substrate, and method of manufacturing the same

FILING FEE	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time)
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